The RF Line **UHF Power Amplifiers**

... designed specifically for the Pan European digital 2.0 watt, GSM hand-held radio. The MHW903, MHW953 and MHW954 are capable of wide power range control, operate from a 7.2 volt supply and require 1.0 mW (MHW903/953) or 100 mW (MHW954) of RF input power.

• Specified 7.2 Volt Characteristics:

RF Input Power — 1.0 mW (0 dBm) MHW903/953; 100 mW (20 dBm) MHW954 RF Output Power — 3.5 W

Minimum Gain — 35.4 dB (MHW903/953) or 15.4 dB (MHW954)

Harmonics — -35 dBc Max @ 2.0 f_O (MHW930/953) or

-30 dBc Max @ 2.0 fo (MHW954)

- New Biasing and Control Techniques Providing Dynamic Range and Control Circuit Bandwidth Ideal for GSM
- Low Control Current
- 50 Ohm Input/Output Impedances
- · Guaranteed Stability and Ruggedness
- Test fixture circuit board photomaster available upon request by contacting RF Tactical Marketing in Phoenix, AZ.

MAXIMUM RATINGS (Flange Temperature = 25°C)

Rating	Symbol	Value	Unit
DC Supply Voltage	V_{S1}, V_{S2}, V_{S3}	9.0	Vdc
DC Bias Voltage (MHW903/953) (MHW954)	V _b	5.25 4.75	Vdc
DC Control Voltage (MHW903/953 only)	V _{cont}	3.0	Vdc
RF Input Power (MHW903/953) (MHW954)	P _{in}	2.0 400	mW
RF Output Power (V _S = 9.0 Vdc)	P _{out}	4.5	W
Operating Case Temperature Range Storage Temperature Range	T _C T _{stg}	-30 to +100	°C

ELECTRICAL CHARACTERISTICS ($V_{S1} = V_{S2} = V_{S3} = 7.2 \text{ Vdc}$; $V_b = 5.0 \text{ Vdc for MHW903/953}$) ($V_{S1} = V_{S2} = 7.2 \text{ Vdc}$; $V_b = 4.5 \text{ Vdc for MHW954}$)

(T_C = 25°C; 50 ohm system, unless otherwise noted)

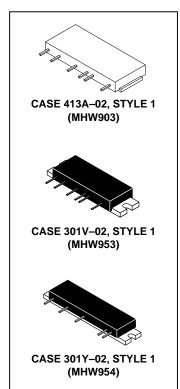
Characteristic		Min	Max	Unit
Frequency Range	BW	890	915	MHz
Power Gain (P _{out} = 3.5 mW) MHW903/953 (1) MHW954 (2)	Gp	35.4 15.4	_	dB
Control Current (P _{out} = 3.5 W; P _{in} = 1.0 mW) MHW903/953 only (1)	I _{cont}	_	1.0	mA
Supply Current (P _{out} = 3.5 W; P _{in} = 1.0 mW) MHW903/953 only (1)	Ib	_	85	mA
Leakage Current ($P_{in} = 0 \text{ mW}$; $V_{cont} = V_b = 0 \text{ Vdc}$; $V_{s1} = V_{s2} = V_{s3} = 9.0 \text{ Vdc}$ for MHW903/953. $P_{in} = 0 \text{ mW}$; $V_b = 0 \text{ Vdc}$; $V_{s1} = V_{s2} = 9.0 \text{ Vdc}$ for MHW954)	ΙL		1.0 200	mΑ μΑ
Input VSWR (P _{out} = 3.5 W; P _{in} = 1.0 mW) MHW903/953 (1) (P _{out} = 3.5 W) MHW954 (2)	VSWR _{in}	_	2.0:1	_

NOTES:

- 1. Adjust V_{cont} for specified P_{out} ; duty cycle = 12.5%, period = 4.6 ms
- 2. Adjust P_{in} for specified P_{out}; duty cycle = 12.5%, period = 4.6 ms

MHW903 MHW953 MHW954

3.5 W 890 to 915 MHz RF POWER AMPLIFIERS



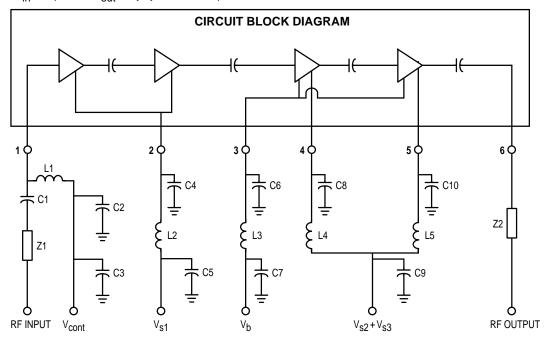
REV 6

(T_C = 25°C; 50 ohm system, unless otherwise noted)

Characteristic		Min	Max	Unit
Efficiency (P _{out} = 3.5 W; P _{in} = 1.0 mW) MHW903/953 (1) (P _{out} = 3.5 W) MHW954 (2)		40	_	%
Harmonics (P_{out} = 3.5 W; P_{in} = 1.0 mW) MHW903/953 (1) 2.0 f ₀ 3.0 f ₀ (P_{out} = 3.5 W) MHW954 (2) 2.0 f ₀ 3.0 f ₀	_	_ _ _ _	-35 -45 -30 -40	dBc
Noise Power (In 30 kHz Bandwidth, 20 MHz above f_0) ($T_C = 25^{\circ}C - 100^{\circ}C$) ($P_{out} = 0.3 - 3.5$ W; $V_{s1} = V_{s2} = V_{s3} = 6.25 - 9.0$ Vdc, $P_{in} = 1.0$ mW) MHW903/953 (1) ($P_{out} = 0.3 - 3.5$ W; $V_{s1} = V_{s2} = 6.25 - 9.0$ Vdc) MHW954 (2)			-65 -75	dBm
Output Power, Low Voltage (P_{in} = 1.0 mW; V_{S1} = V_{S2} = V_{S3} = 6.25 Vdc; V_{cont} = 3.0 Vdc) MHW903/953 (P_{in} = 100 mW; V_{S1} = V_{S2} = 6.25 Vdc) MHW954		2.0 2.3	_	W
Isolation ($P_{in} = 1.0 \text{ mW}$; $V_{cont} = 0 \text{ Vdc}$; $V_{s1} = V_b = 0-5 \text{ Vdc}$) MHW903/953 only (1)		_	-36	dBm
3.0 dB V_{cont} Bandwidth (P_{in} = 1.0 mW; P_{out} = 0.03–3.5 W) MHW903/953 only (1)		1.0	_	MHz
% AM In Output (P _{Out} = 0.035-3.5 W; 135 kHz, 1% AM on Input) MHW954 only (2)		_	6	%
Load Mismatch Stress (P_{in} = 2.0 mW; P_{out} = 3.5 W; V_{S1} = V_{S2} = V_{S3} = 9.0 Vdc) MHW903/953 (1) (P_{out} = 3.5 W; V_{b} = 4.75 Vdc; V_{S1} = V_{S2} = 9.0 Vdc) MHW954 (2) (Load VSWR = 10:1, All Phase Angles at Frequency of Test)		No degradation in output power before and after test		
Stability $ \begin{array}{l} \text{Stability} \\ \text{(P}_{in} = 0.5 \text{ to } 2.0 \text{ mW; P}_{out} = 0.03 - 3.5 \text{ W; V}_{S1} = \text{V}_{S2} = \text{V}_{S3} = 6.0 \text{ to } 9.0 \text{ Vdc) MHW903/953 (1)} \\ \text{(P}_{out} = 0.03 - 3.5 \text{ W; V}_{S1} = \text{V}_{S2} = 6.0 \text{ to } 9.0 \text{ Vdc) MHW954 (2)} \\ \text{(Load VSWR} = 6:1, Source VSWR} = 3:1, \text{ All Phase Angles at Frequency of Test)} \end{array} $		All spurious outputs more than 60 dB below desired signal		

NOTES:

- 1. Adjust V_{cont} for specified P_{out} ; duty cycle = 12.5%, period = 4.6 ms
- 2. Adjust P_{in} for specified P_{out}; duty cycle = 12.5%, period = 4.6 ms



PIN DESIGNATIONS:

Pin 1 — RF Input Power @ 0 dBm and Control Voltage @ 0-3.0 Vdc

Pin 2 — First and Second Stage Collector Supply Voltage @ 7.2 Vdc

Pin 3 — Trickle Base Bias Voltage @ 5.0 Vdc

Pin 4 — Third Stage Collector Supply Voltage @ 7.2 Vdc

Pin 5 — Fourth Stage Collector Supply Voltage @ 7.2 Vdc

Pin 6 — RF Output Power @ 3.5 W

ELEMENT VALUES:

C1=C2= 0.018 μF

C4=C6=C8=C10= 0.1 μF

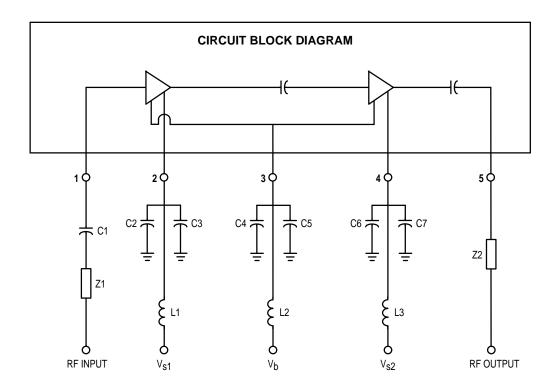
 $C3=C5=C7=C9 = 1.0 \mu F Tant.$

 $L1-L3 = 0.29 \,\mu\text{H}$ Choke

L4, L5 = $0.15 \,\mu\text{H}$ Choke

Z1, Z2 = 50 Ohm Microstrip

Figure 1. Test Circuit Diagram — MHW903/953



PIN DESIGNATIONS:

Pin 1 — RF Input Power @ 20 dBm Max Adjust for Output Power

Pin 2 — First Stage Collector Voltage @ 7.2 Vdc

Pin 3 — Trickle Bias Voltage @ 4.5 Vdc

Pin 4 — Third Stage Collector Supply @ 7.2 Vdc

Pin 5 — RF Output Power @ 3.5 W Nominal

ELEMENT VALUES:

 $C1=C2=C4=C6=0.018~\mu F$ $C3=C5=C7=2.2~\mu F$

L1, L2 = $0.29 \, \mu H$

 $L3=0.2\,\mu H$

Z1, Z2 = 50 Ohm Microstrip

Figure 2. Test Circuit Diagram — MHW954

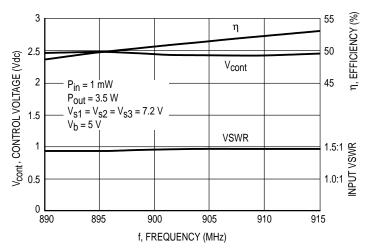


Figure 3. Control Voltage, Efficiency and Input VSWR versus Frequency

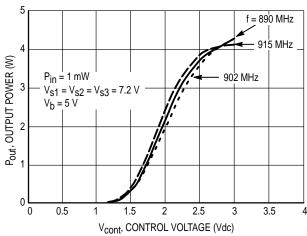
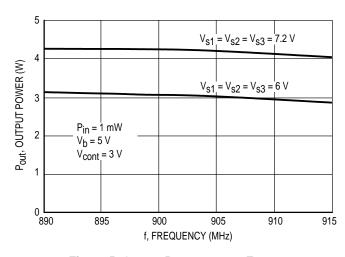


Figure 4. Output Power versus Control Voltage



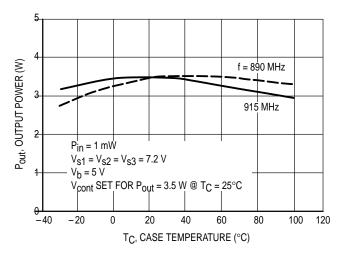


Figure 5. Output Power versus Frequency

Figure 6. Output Power versus Case Temperature

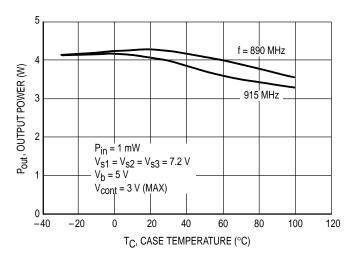


Figure 7. Output Power versus Case Temperature at Maximum Control Voltage

APPLICATIONS INFORMATION

NOMINAL OPERATION

All electrical specifications are based on the nominal conditions of $V_{S1} = V_{S2} = V_{S3} = 7.2$ Vdc (Pins 2, 4, 5) and $V_{b} = 5.0$ Vdc (Pin 3) for MHW903/953. Nominal conditions are $V_{S1} = V_{S2} = 7.2$ Vdc (Pins 2 and 4) and $V_{b} = 4.5$ Vdc (Pin 3) for MHW954. With these conditions, maximum current density on any device is 1.5×10^5 A/cm² and maximum die temperature is 165° C. While the modules are designed to have excess gain margin with ruggedness, operation of these units outside the published specifications is not recommended unless prior communications regarding intended use have been made with the factory representative.

GAIN CONTROL

The module output power should be limited to specified value. The preferred method of power control for the MHW903/953 is to fix $V_{S1} = V_{S2} = V_{S3} = 7.2$ Vdc, $V_b = 5.0$ Vdc, P_{in} (Pin 1) at 1.0 mW, and vary V_{cont} (Pin 1) voltage. For the MHW954, fix $V_{S1} = V_{S2} = 7.2$ Vdc and $V_b = 4.5$ Vdc; then vary P_{in} (Pin 1) to control P_{out} (Pin 5).

DECOUPLING

Due to the high gain of the four stages and the module size limitation, external decoupling networks require careful consideration, Pins 2, 3, 4 and 5 are internally bypassed with a $0.018\,\mu\text{F}$ chip capacitor which is effective for frequencies from

5.0 MHz through 940 MHz. For bypassing frequencies below 5.0 MHz, networks equivalent to that shown in Figure 1 are recommended. Inadequate decoupling will result in spurious outputs at certain operating frequencies and certain phase angles of input and output VSWR.

MOUNTING CONSIDERATIONS

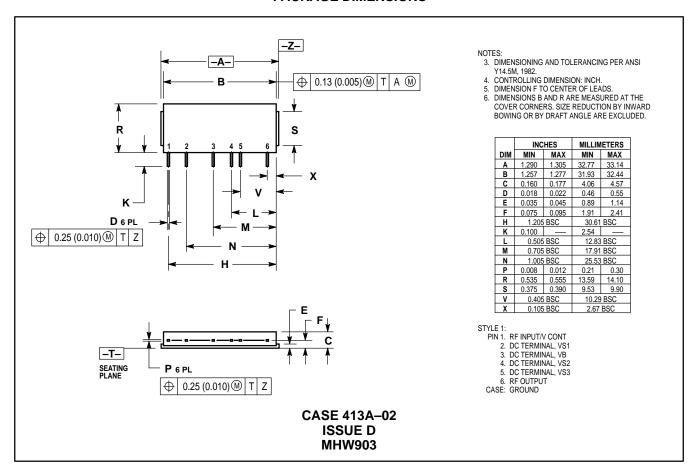
For the MHW903 Series module, mounting is generally accomplished by soldering the flange to a suitable heat sink. This can be done with a low temperature solder such as 52% In, 48% Sn and type "R" Flux which liquifies below 150°C. Under no circumstances should the MHW903 Series modules be heated to a temperature greater than ≈165°C. Internal construction of the module has been achieved using 36% Tin, 62% lead, 2% silver solder which liquifies at 179−180°C.

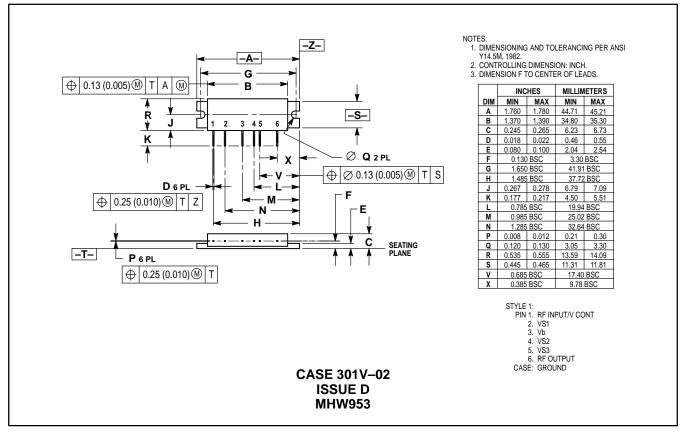
The modules are NOT hermetic. Do not immerse a module in a flux cleaning solution or other liquids under any circumstances.

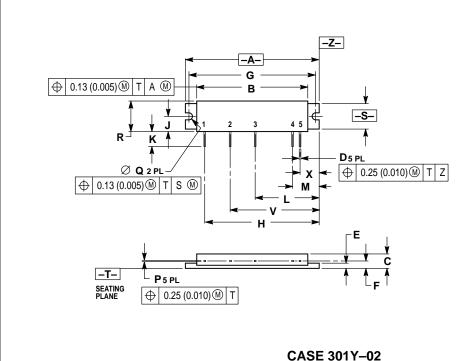
LOAD MISMATCH

During final test each module is load mismatch tested in a fixture having the identical decoupling networks described in Figure 1. Electrical conditions are $V_{S1} = V_{S2} = V_{S3} = 9.0$ Vdc (Pins 2, 4, 5), and $V_{b} = 5.0$ Vdc (Pin 3), $P_{in} = 2.0$ mW (12.5% duty cycle, 4.6 ms period), VSWR equal to 10:1, and output power equal to 4.5 watts.

PACKAGE DIMENSIONS







- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION F TO CENTER OF LEADS.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	1.970	1.990	50.04	50.55
В	1.570	1.590	39.88	40.39
С	0.245	0.265	6.23	6.73
D	0.018	0.022	0.46	0.56
Е	0.100	0.115	2.54	2.92
F	0.147 BSC		3.73 BSC	
G	1.860 BSC		47.24 BSC	
Н	1.625 BSC		41.28 BSC	
J	0.267	0.278	6.78	7.06
K	0.177	0.217	4.50	5.51
L	0.825 BSC		20.96 BSC	
M	0.425 BSC		10.80 BSC	
Р	0.008	0.012	0.20	0.30
Q	0.120	0.130	3.05	3.30
R	0.535	0.555	13.59	14.10
S	0.445	0.465	11.30	11.81
٧	1.225	BSC	31.12 BSC	
Х	0.325 BSC		8.26 BSC	

STYLE 1

- PIN 1. RF INPUT 2. DC TERMINAL, Vs1

 - DC TERMINAL, Vb DC TERMINAL, Vs2 RF OUTPUT

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